



HIGH GAIN, LOW $V_{CE(SAT)}$ NPN BIPOLAR TRANSISTOR

Features

- High Gain Low Vcesat NPN transistor
- Very Low Rcesat
- High ICM capability
- 1.5A Continuous Current Rating
- Ultra-Small Surface mount Package
- Qualified to AEC-Q101 Standards for High Reliability
- Lead, Halogen and Antimony Free, RoHS Compliant (Note 1)
- "Green" Device (Note 2)
- ESD rating: 400V-MM, 8KV-HBM

Mechanical Data

- Case: DFN1411-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper lead frame. Solderable per MIL-STD-202, Method 208
- Weight: 0.003 grams (approximate)

Applications

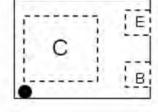
- MOSFET and IGBT gate driving
- DC-DC conversion
- Interface between low voltage IC and Load
- LED driving



Top view



Bottom view



Device Symbol

Pin-out Top view

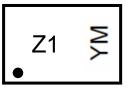
Ordering Information

ĺ	Product	Status	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
	Tiouuot	Olulus	marking			equility per reer
	ZXTN26020DMFTA	Active	Z1	7	8	3000

Notes: 1. No purposefully added lead. Halogen and Antimony Free.

2. Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com

Marking Information



 $\begin{array}{l} Z1 = \mbox{Product Type Marking Code} \\ YM = \mbox{Date Code Marking} \\ Y = \mbox{Year (ex: } W = 2009) \\ M = \mbox{Month (ex: } 9 = \mbox{September)} \end{array}$

Date Code Key

Duie Obue hey												
Year	200	9	2010		2011	20	12	2013		2014	1	2015
Code	W		Х		Y		Z	А		В		С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D





ZXTN26020DMF

Maximum Ratings

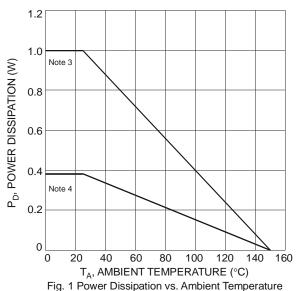
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	20	V
Collector-Emitter Voltage	V _{CEO}	20	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current (Note 4)	lc	1.5	A
Peak Pulse Current	I _{CM}	4	A
Base Current	IB	0.5	A

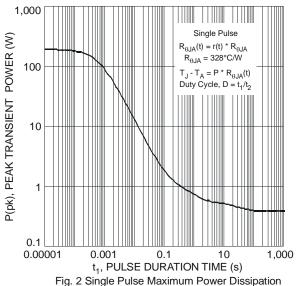
Thermal Characteristics

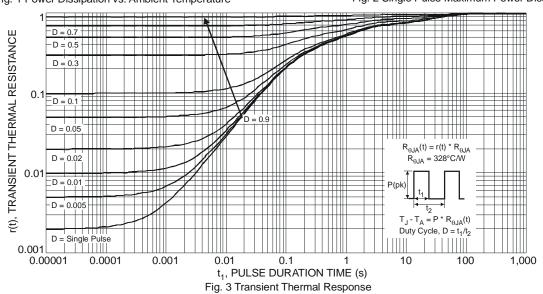
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3)	PD	1	W
Power Dissipation (Note 4)	PD	380	mW
Thermal Resistance, Junction to Ambient (Note 3) @ T _A = 25°C	$R_{ ext{ heta}JA}$	125	°C/W
Thermal Resistance, Junction to Ambient (Note 3) @ T _A = 25°C	R _{0JA}	330	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C

Notes: 3. Device mounted on FR-4 PCB with 1inch square pads.

4. Device mounted on FR-4 PCB with minimum recommended pad layout







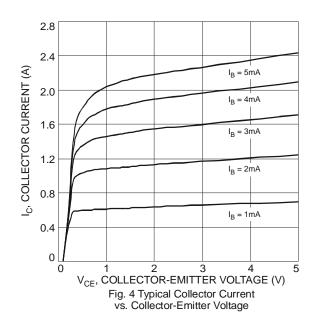


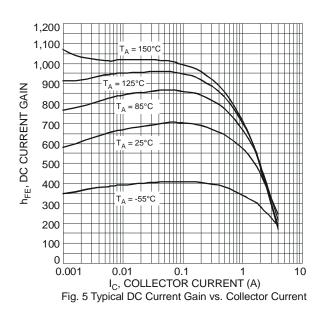
ZXTN26020DMF

Electrical Characteristics (at T_A = 25°C unless otherwise specified)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	V _{(BR)CBO}	20	_		V	$I_{C} = 100 \mu A, I_{E} = 0 A$
Collector-Emitter Breakdown Voltage (Note 5)	V _{(BR)CEO}	20	_		V	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0 {\rm A}$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	7			V	$I_{E} = 100 \mu A, I_{C} = 0 A$
Emitter-Collector Breakdown Voltage	V _{(BR)ECO}	5			V	$I_{\rm E} = 100 \mu A$, $I_{\rm B} = 0 A$
Collector Cutoff Current	lcbo	_	_	100 0.5	nA μA	$V_{CB} = 20V, I_E = 0A$ $V_{CB} = 20V, I_E = 0, T_A = 125^{\circ}C$
Emitter Cutoff Current	Ices	_	_	100	nA	$V_{CE} = 20V, V_{BE} = 0V$
Base Cutoff Current	lebo			100	nA	$V_{BE} = 5.6V, I_{C} = 0A$
DC Current Gain (Note 5)	h _{FE}	300 290 270 200		1000 	_	$V_{CE} = 2V, I_C = 100mA$ $V_{CE} = 2V, I_C = 0.5A$ $V_{CE} = 2V, I_C = 1A$ $V_{CE} = 2V, I_C = 2A$
Collector-Emitter Saturation Voltage (Note 5)	V _{CE(SAT)}			45 70 125 225 225 290	mV mV mV mV mV mV	$\begin{split} I_{C} &= 100\text{mA}, I_{B} = 1\text{mA} \\ I_{C} &= 500\text{mA}, I_{B} = 25\text{mA} \\ I_{C} &= 1\text{A}, I_{B} = 50\text{mA} \\ I_{C} &= 1.5\text{A}, I_{B} = 30\text{mA} \\ I_{C} &= 2\text{A}, I_{B} = 100\text{mA} \\ I_{C} &= 2\text{A}, I_{B} = 40\text{mA} \end{split}$
Equivalent On-Resistance	R _{CE(SAT)}	_	90		mΩ	I _C = 1A, I _B = 50mA
Base-Emitter Turn-On Voltage	V _{BE(ON)}	_		1.2	V	$V_{CE} = 2V, I_C = 2A$
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	_	1.1	V	$I_{\rm C} = 2A, I_{\rm B} = 100 {\rm mA}$
Output Capacitance (Note 5)	Cobo	_		20	pF	V _{CB} = 10V, f = 1.0MHz
Input Capacitance (Note 5)	C _{ibo}	—	_	150	pF	V _{EB} = 0.5V, f = 1.0MHz
Current Gain-Bandwidth Product	f _T	—	260	_	MHz	$V_{CE} = 10V$, $I_C = 50mA$, f = 100MHz
Turn-On Time	t _{on}	_	60		ns	
Delay Time	t _d	_	20		ns	
Rise Time	tr		40		ns	$V_{CC} = 10V, I_{C} = 1A$
Turn-Off Time	t _{off}	_	225	_	ns	$I_{B2} = -I_{B1} = 50 \text{mA}$
Storage Time	ts	_	205		ns	
Fall Time	t _f		20		ns	

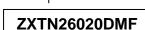
Notes: 5. Short duration pulse test used to minimize self-heating effect.

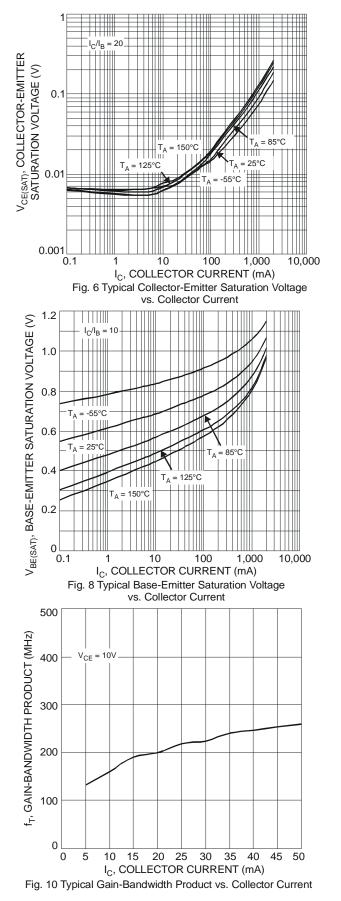


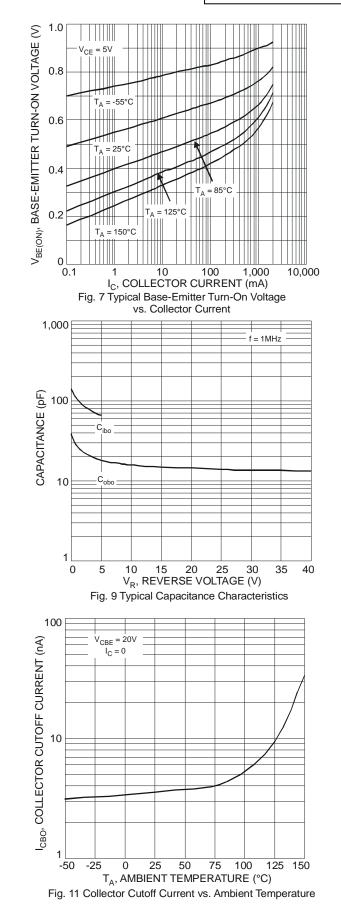




A Product Line of Diodes Incorporated

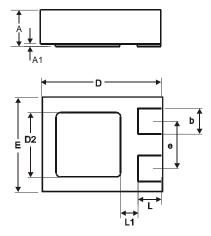






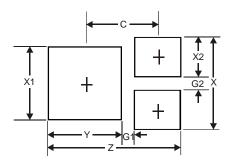


Package Outline Dimensions



DFN1411-3						
Dim	Min	Max	Тур			
Α	0.47	0.53	0.50			
A1	0	0.05	0.02			
b	0.25	0.35	0.30			
D	1.35	1.475	1.40			
D2	0.65	0.85	0.75			
Е	1.05	1.18	1.10			
е			0.55			
L	0.225	0.325	0.275			
L1			0.20			
All Dimensions in mm						

Suggested Pad Layout



Dimensions	Value (in mm)
Z	1.38
G1	0.15
G2	0.15
Х	0.95
X1	0.75
X2	0.40
Y	0.75
С	0.76



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